

GP10-4003E-M3/54



Vishay / Semiconductor - Diodes Division

DIODE GEN PURP 200V 1A DO204AL

Lead free / RoHS Compliant

Discrete Semiconductor Products

[GP10-4003E-M3/54.pdf](#)

Buy Now

Out Stock

0 pcs

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

We can supply Vishay / Semiconductor - Diodes Division GP10-4003E-M3/54, use the request quote form to request GP10-4003E-M3/54 pirce, Vishay / Semiconductor - Diodes Division Datasheet PDF and lead time.Zeanoit.com is a professional electronic components distributor. With 3+ Million line items of available electronic components can ship in short lead-time, over 250 thousand part numbers of electronic components in stock for immediately delivery, which may include part number GP10-4003E-M3/54.The price and lead time for GP10-4003E-M3/54 depending on the quantity required, availability and warehouse location.

Shopping Process

1

Confirm the product

2

submit the order

3

payment

4

wait for delivery

5

receive the goods

Specifications

| | |
|---|--|
| Voltage - Forward (Vf) (Max) @ If: | 1.1V @ 1A |
| Voltage - DC Reverse (Vr) (Max): | 200V |
| Supplier Device Package: | DO-204AL (DO-41) |
| Speed: | Standard Recovery >500ns, > 200mA (Io) |
| Series: | Automotive, AEC-Q101, Superrectifier® |
| Reverse Recovery Time (trr): | 3µs |
| Packaging: | Tape & Reel (TR) |
| Package / Case: | DO-204AL, DO-41, Axial |
| Operating Temperature - Junction: | -65°C ~ 175°C |
| Mounting Type: | Through Hole |
| Diode Type: | Standard |
| Current - Reverse Leakage @ Vr: | 5µA @ 200V |
| Current - Average Rectified (Io): | 1A |
| Capacitance @ Vr, F: | 8pF @ 4V, 1MHz |

Related products



GP10-4003E-E3/53

DIODE GEN PURP 200V 1A DO204AL

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RFQ



GP10-4002HM3/54

DIODE GEN PURP 100V 1A DO204AL

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GP10-4003EHE3/73

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GP10-4002HE3/53

DIODE GEN PURP 100V 1A DO204AL

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RFQ

Guess You May Looking For



SIT1602BC-13-XXN-12.000000E

-20 TO 70C, 2520, 50PPM, 2.25V-3

[SITIME](#)

RFQ

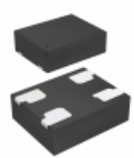


SIT1602BI-73-18E-33.330000E

-40 TO 85C, 2016, 50PPM, 1.8V, 3

[SITIME](#)

RFQ

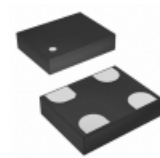


SIT1602BI-13-18E-19.200000D

-40 TO 85C, 2520, 50PPM, 1.8V, 1

[SITIME](#)

RFQ



SIT1602BC-22-28E-35.840000E

-20 TO 70C, 3225, 25PPM, 2.8V, 3

[SITIME](#)

RFQ



SIT1602BC-31-28E-50.000000T

-20 TO 70C, 5032, 20PPM, 2.8V, 5

[SITIME](#)

RFQ

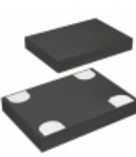


SIT1602BC-31-18E-31.250000T

-20 TO 70C, 5032, 20PPM, 1.8V, 3

[SITIME](#)

RFQ

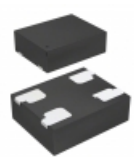


SIT1602BC-82-XXS-72.000000T

-20 TO 70C, 7050, 25PPM, 2.25V-3

[SITIME](#)

RFQ

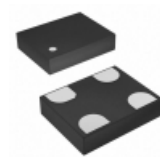


SIT1602BI-12-33E-24.576000D

OSC MEMS 24.5760MHZ LVCMOS SMD

[SITIME](#)

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SIT1602BC-23-XXN-48.000000G

-20 TO 70C, 3225, 50PPM, 2.25V-3

[SITIME](#)

RFQ



SIT1602BC-72-33N-4.000000G

-20 TO 70C, 2016, 25PPM, 3.3V, 4

[SITIME](#)

RFQ